

## 2.0A/1.5A LDO REGULATOR

NO. EA-125-111027

### OUTLINE

The R1171x Series are CMOS-based positive voltage regulator ICs. The R1171x Series have features of low dropout voltage, high output voltage accuracy, low consumption current. Each of these ICs consists of a voltage reference unit, an error amplifier, resistor net for setting output voltage, a current limit circuit at short mode, a chip enable circuit, and thermal shutdown circuit. The output voltage of R1171 is fixed in the IC.

Low consumption current by the merit of CMOS process and built-in transistors with low ON-resistance make low dropout voltage and chip enable function prolongs the battery life. These regulators are remarkable improvement on the current regulators in terms of input transient response, and load transient response.

Thus, the R1171x Series are suitable for various power sources.

Since the packages for these ICs are high wattage HSOP-6J package, TO-252-5-P1, high density mounting of the ICs on boards is possible.

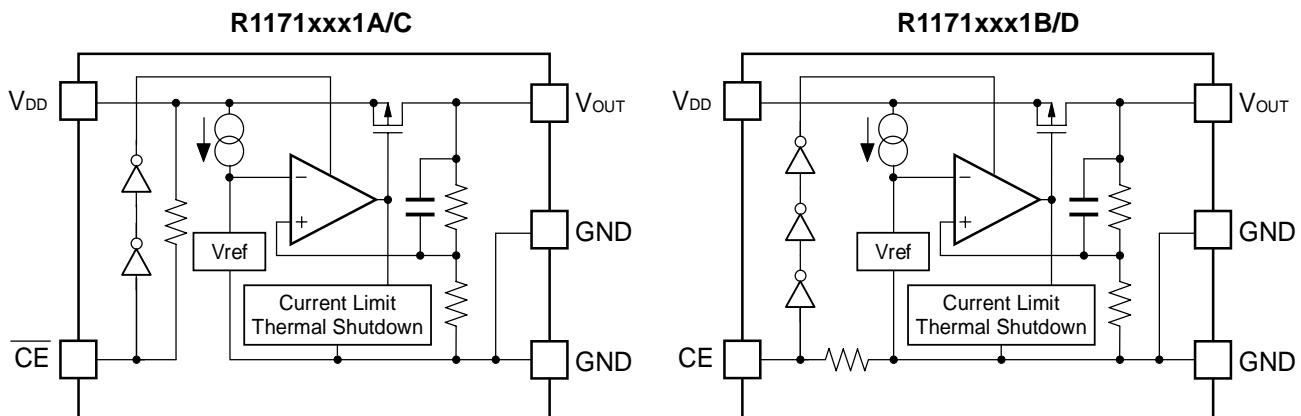
### FEATURES

- Supply Current ..... Typ. 130 $\mu$ A
- Standby Current ..... Typ. 0.1 $\mu$ A
- Output Current ..... Min. 1.5A ( $V_{IN}=V_{OUT}+1.0V$ , R1171Sxx1A/B)  
Min. 2.0A ( $V_{IN}=V_{OUT}+1.0V$ , R1171Jxx1C/D)
- Input Voltage ..... 2.1V to 6.0V
- Output Voltage ..... 1.5V to 5.0V (0.1V steps) (R1171Sxx1A/B)  
1.8V to 5.0V (0.1V steps) (R1171Jxx1C/D)  
(For other voltages, please refer to MARK INFORMATIONS.)
- Output Voltage Accuracy .....  $\pm 2.0\%$
- Dropout Voltage ..... Typ. 0.09V ( $V_{OUT}=3.0V$ ,  $I_{OUT}=300mA$ )
- Temperature-drift Coefficient of Output Voltage ..... Typ.  $\pm 100ppm/^{\circ}C$
- Line Regulation ..... Typ. 0.05%/V
- Packages ..... HSOP-6J, TO-252-5-P1
- Built-in Current Limit Circuit
- Built-in Thermal Shutdown Circuit
- Ceramic capacitor for phase compensation .....  $C_{IN}=C_{OUT}=\text{Ceramic } 10\mu F$  ( $V_{OUT}<1.8V$ )  
 $C_{IN}=C_{OUT}=\text{Ceramic } 4.7\mu F$  ( $V_{OUT} \geq 1.8V$ )

### APPLICATIONS

- Local Power source for Notebook PC.
- Local Power source for portable appliances, cameras, and videos.
- Local Power source for equipment of battery-use.
- Local Power source for home appliances.

## BLOCK DIAGRAMS



## SELECTION GUIDE

The output voltage, chip enable polarity, package for the ICs can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1171Sxx1*-E2-FE	HSOP-6J	1,000 pcs	Yes	Yes
R1171Jyy1\$-T1-F	TO-252-5-P1	3,000 pcs	Yes	No

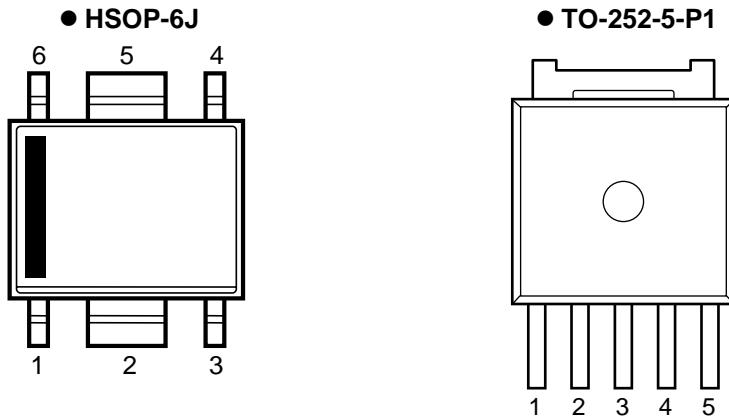
xx: The output voltage can be designated in the range from 1.5V(15) to 5.0V(50) in 0.1V steps.  
(For other voltages, please refer to MARK INFORMATIONS.)

yy: The output voltage can be designated in the range from 1.8V(18) to 5.0V(50) in 0.1V steps.  
(For other voltages, please refer to MARK INFORMATIONS.)

\* : CE pin polarity are options as follows.  
(A) "L" active  
(B) "H" active

\$ : CE pin polarity are options as follows.  
(C) "L" active  
(D) "H" active

## PIN CONFIGURATIONS



## PIN DESCRIPTIONS

### • HSOP-6J

Pin No	Symbol	Pin Description
1	$V_{OUT}$	Output Pin
2	GND	Ground Pin
3	$\overline{CE}$ or CE	Chip Enable Pin
4	NC	No Connection
5	GND	Ground Pin
6	$V_{DD}$	Input Pin

### • TO-252-5-P1

Pin No	Symbol	Pin Description
1	$V_{OUT}$	Output Pin
2	$\overline{CE}$ or CE	Chip Enable Pin
3	GND	Ground Pin
4	GND	Ground Pin
5	$V_{DD}$	Input Pin

\*) No.3 and No.4 pins must be wired short each other and connected to the GND plane when it is mounted on board.

## ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
$V_{IN}$	Input Voltage	7.0	V
$V_{CE}$	Input Voltage ( $\overline{CE}$ or CE Input Pin)	-0.3 to $V_{IN}+0.3$	V
$V_{OUT}$	Output Voltage	-0.3 to $V_{IN}+0.3$	V
$P_D$	Power Dissipation (HSOP-6J) <sup>*1</sup>	1700	mW
	Power Dissipation (TO-252-5-P1) <sup>*1</sup>	1900	
$T_{opt}$	Operating Temperature	-40 to 85	°C
$T_{stg}$	Storage Temperature	-55 to 125	°C

\*) For Power Dissipation, please refer to PACKAGE INFORMATION.

### ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

### RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

## ELECTRICAL CHARACTERISTICS

### • R1171Sxx1A

Topt=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V <sub>OUT</sub>	Output Voltage	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V, I <sub>OUT</sub> =200mA	>0.98		>1.02	V
ΔV <sub>OUT</sub> / ΔI <sub>OUT</sub>	Load Regulation	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V 1mA ≤ I <sub>OUT</sub> ≤ 300mA		10	60	mV
V <sub>DIF</sub>	Dropout Voltage	I <sub>OUT</sub> =300mA	1.5 ≤ V <sub>OUT</sub> <1.6	0.16	0.35	V
			1.6 ≤ V <sub>OUT</sub> <1.7	0.14	0.32	
			1.7 ≤ V <sub>OUT</sub> <1.8	0.13	0.28	
			1.8 ≤ V <sub>OUT</sub> <2.0	0.12	0.24	
			2.0 ≤ V <sub>OUT</sub> <2.5	0.10	0.21	
			2.5 ≤ V <sub>OUT</sub> ≤ 5.0	0.09	0.18	
I <sub>SS</sub>	Supply Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V, V <sub>CE</sub> =0V		130	320	μA
I <sub>STANDBY</sub>	Standby Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V, V <sub>IN</sub> =V <sub>CE</sub>		0.1	2.0	μA
ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>	Line Regulation	I <sub>OUT</sub> =200mA	Refer to the following table			
RR	Ripple Rejection	f=1kHz, Ripple 0.5Vp-p				
V <sub>IN</sub>	Input Voltage		2.1		6.0	V
ΔV <sub>OUT</sub> / ΔT <sub>opt</sub>	Output Voltage Temperature Coefficient	I <sub>OUT</sub> =10mA -40°C ≤ T <sub>opt</sub> ≤ 85°C		±100		ppm/°C
I <sub>LIM</sub>	Output Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V	1.5			A
I <sub>SC</sub>	Short Current Limit	V <sub>OUT</sub> =0V		200		mA
R <sub>P</sub>	Pull-up resistance for CE pin		2.5	5.0	10.0	MΩ
V <sub>CEH</sub>	CE Input Voltage "H"		1.2		V <sub>IN</sub>	V
V <sub>CEL</sub>	CE Input Voltage "L"		0		0.25	V
T <sub>TSD</sub>	Thermal Shutdown Detector Threshold Temperature	Junction Temperature		150		°C
T <sub>TSR</sub>	Thermal Shutdown Released Temperature	Junction Temperature		120		°C

### • Line Regulation by Output Voltage

Topt=25°C

Output Voltage V <sub>OUT</sub> (V)	Line Regulation ΔV <sub>OUT</sub> /ΔV <sub>IN</sub> (%/V)		
	Condition	Typ.	Max.
1.5 ≤ V <sub>OUT</sub> < 1.6	I <sub>OUT</sub> =200mA, 2.1V ≤ V <sub>IN</sub> ≤ 6.0V	0.05	0.30
1.6 ≤ V <sub>OUT</sub> ≤ 5.0	I <sub>OUT</sub> =200mA, V <sub>OUT</sub> +0.5V ≤ V <sub>IN</sub> ≤ 6.0V		

### • Ripple Rejection by Output Voltage

Topt=25°C

Output Voltage V <sub>OUT</sub> (V)	Ripple Rejection RR (dB)	
	Condition	Typ.
1.5 ≤ V <sub>OUT</sub> < 4.7	f=1kHz, Ripple 0.5Vp-p, V <sub>IN</sub> -V <sub>OUT</sub> =1.0V	50
4.7 ≤ V <sub>OUT</sub> ≤ 5.0	f=1kHz, Ripple 0.5Vp-p, V <sub>IN</sub> =5.75V	

## R1171x

- R1171Sxx1B

T<sub>opt</sub>=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V <sub>OUT</sub>	Reference Voltage for Adjustable Voltage Regulator	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V I <sub>OUT</sub> =200mA	x0.98		x1.02	V
ΔV <sub>OUT</sub> / ΔI <sub>OUT</sub>	Load Regulation	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V 1mA ≤ I <sub>OUT</sub> ≤ 300mA		10	60	mV
V <sub>DIF</sub>	Dropout Voltage	I <sub>OUT</sub> =300mA	1.5 ≤ V <sub>OUT</sub> <1.6		0.16	0.35
			1.6 ≤ V <sub>OUT</sub> <1.7		0.14	0.32
			1.7 ≤ V <sub>OUT</sub> <1.8		0.13	0.28
			1.8 ≤ V <sub>OUT</sub> <2.0		0.12	0.24
			2.0 ≤ V <sub>OUT</sub> <2.5		0.10	0.21
			2.5 ≤ V <sub>OUT</sub> ≤ 5.0		0.09	0.18
I <sub>SS</sub>	Supply Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V, V <sub>CE</sub> =V <sub>IN</sub>		130	320	μA
I <sub>standby</sub>	Standby Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V, V <sub>CE</sub> =0V		0.1	2.0	μA
ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>	Line Regulation	I <sub>OUT</sub> =200mA	Refer to the following table			
RR	Ripple Rejection	f=1kHz, Ripple 0.5Vp-p				
V <sub>IN</sub>	Input Voltage		2.1		6.0	V
ΔV <sub>OUT</sub> / ΔT <sub>opt</sub>	Output Voltage Temperature Coefficient	I <sub>OUT</sub> =10mA -40°C ≤ T <sub>opt</sub> ≤ 85°C		±100		ppm/°C
I <sub>LIM</sub>	Output Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V	1.5			A
I <sub>SC</sub>	Short Current Limit	V <sub>OUT</sub> =0V		200		mA
R <sub>PD</sub>	Pull-down resistance for CE pin		2.5	5.0	10.0	MΩ
V <sub>CEH</sub>	CE Input Voltage "H"		1.2		V <sub>IN</sub>	V
V <sub>CEL</sub>	CE Input Voltage "L"		0		0.25	V
T <sub>TSD</sub>	Thermal Shutdown Detector Threshold Temperature	Junction Temperature		150		°C
T <sub>TSR</sub>	Thermal Shutdown Released Temperature	Junction Temperature		120		°C

- Line Regulation by Output Voltage

T<sub>opt</sub>=25°C

Output Voltage V <sub>OUT</sub> (V)	Line Regulation ΔV <sub>OUT</sub> /ΔV <sub>IN</sub> (%/V)		
	Condition	Typ.	Max.
1.5 ≤ V <sub>OUT</sub> < 1.6	I <sub>OUT</sub> =200mA, 2.1V ≤ V <sub>IN</sub> ≤ 6.0V	0.05	0.30
1.6 ≤ V <sub>OUT</sub> ≤ 5.0	I <sub>OUT</sub> =200mA, V <sub>OUT</sub> +0.5V ≤ V <sub>IN</sub> ≤ 6.0V		

- Ripple Rejection by Output Voltage

T<sub>opt</sub>=25°C

Output Voltage V <sub>OUT</sub> (V)	Ripple Rejection RR (dB)	
	Condition	Typ.
1.5 ≤ V <sub>OUT</sub> < 4.7	f=1kHz, Ripple 0.5Vp-p, V <sub>IN</sub> -V <sub>OUT</sub> =1.0V	50
4.7 ≤ V <sub>OUT</sub> ≤ 5.0	f=1kHz, Ripple 0.5Vp-p, V <sub>IN</sub> =5.75V	

- R1171Jxx1C

Topt=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V <sub>OUT</sub>	Output Voltage	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V I <sub>OUT</sub> =200mA	×0.98		×1.02	V
ΔV <sub>OUT</sub> / ΔI <sub>OUT</sub>	Load Regulation	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V 1mA ≤ I <sub>OUT</sub> ≤ 300mA		10	60	mV
V <sub>DIF</sub>	Dropout Voltage	I <sub>OUT</sub> =300mA	1.8 ≤ V <sub>OUT</sub> <2.0		0.12	0.24
			2.0 ≤ V <sub>OUT</sub> <2.5		0.10	0.21
			2.5 ≤ V <sub>OUT</sub> ≤ 5.0		0.09	0.18
I <sub>SS</sub>	Supply Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V, V <sub>CE</sub> =0V		130	320	μA
I <sub>standby</sub>	Standby Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V, V <sub>IN</sub> =V <sub>CE</sub>		0.1	2.0	μA
ΔV <sub>OUT</sub> / ΔV <sub>IN</sub>	Line Regulation	I <sub>OUT</sub> =200mA V <sub>OUT</sub> +0.5V ≤ V <sub>IN</sub> ≤ 6V		0.05	0.30	%/V
RR	Ripple Rejection	f=1kHz, Ripple 0.5Vp-p	Refer to the following table			
V <sub>IN</sub>	Input Voltage		2.1		6.0	V
ΔV <sub>OUT</sub> / ΔTopt	Output Voltage Temperature Coefficient	I <sub>OUT</sub> =10mA -40°C ≤ Topt ≤ 85°C		±100		ppm/°C
I <sub>LIM</sub>	Output Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V	2.0			A
I <sub>SC</sub>	Short Current Limit	V <sub>OUT</sub> =0V		200		mA
R <sub>PU</sub>	Pull-up resistance for $\overline{CE}$ pin		2.5	5.0	10.0	MΩ
V <sub>CEH</sub>	$\overline{CE}$ Input Voltage "H"		1.2		V <sub>IN</sub>	V
V <sub>CEL</sub>	$\overline{CE}$ Input Voltage "L"		0		0.25	V
T <sub>TSD</sub>	Thermal Shutdown Detector Threshold Temperature	Junction Temperature		150		°C
T <sub>TSR</sub>	Thermal Shutdown Released Temperature	Junction Temperature		120		°C

- Ripple Rejection by Output Voltage

Topt=25°C

Output Voltage V <sub>OUT</sub> (V)	Ripple Rejection RR (dB)	
	Condition	Typ.
1.8 ≤ V <sub>OUT</sub> < 4.7	f=1kHz, Ripple 0.5Vp-p, V <sub>IN</sub> -V <sub>OUT</sub> =1.0V	50
4.7 ≤ V <sub>OUT</sub> ≤ 5.0	f=1kHz, Ripple 0.5Vp-p, V <sub>IN</sub> =5.75V	

## R1171x

### • R1171Jxx1D

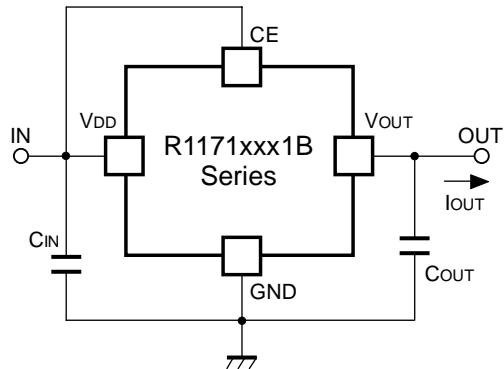
Symbol	Item	Conditions	Min.	Typ.	Max.	Unit	Topt=25°C
V <sub>OUT</sub>	Reference Voltage for Adjustable Voltage Regulator	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V I <sub>OUT</sub> =200mA	×0.98		×1.02	V	
ΔV <sub>OUT</sub> / ΔI <sub>OUT</sub>	Load Regulation	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V 1mA ≤ I <sub>OUT</sub> ≤ 300mA		10	60	mV	
V <sub>DIF</sub>	Dropout Voltage	I <sub>OUT</sub> =300mA	1.8 ≤ V <sub>OUT</sub> <2.0		0.12	0.24	V
			2.0 ≤ V <sub>OUT</sub> <2.5		0.10	0.21	
			2.5 ≤ V <sub>OUT</sub> ≤ 5.0		0.09	0.18	
I <sub>SS</sub>	Supply Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V, V <sub>CE</sub> =V <sub>IN</sub>		130	320	μA	
I <sub>standby</sub>	Standby Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V, V <sub>CE</sub> =0V		0.1	2.0	μA	
ΔV <sub>OUT</sub> / ΔV <sub>IN</sub>	Line Regulation	I <sub>OUT</sub> =200mA V <sub>OUT</sub> +0.5V ≤ V <sub>IN</sub> ≤ 6V		0.05	0.30	%/V	
RR	Ripple Rejection	f=1kHz, Ripple 0.5Vp-p	Refer to the following table				
V <sub>IN</sub>	Input Voltage		2.1		6.0	V	
ΔV <sub>OUT</sub> / ΔT <sub>opt</sub>	Output Voltage Temperature Coefficient	I <sub>OUT</sub> =10mA -40°C ≤ T <sub>opt</sub> ≤ 85°C		±100		ppm/°C	
I <sub>LIM</sub>	Output Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V	2.0			A	
I <sub>SC</sub>	Short Current Limit	V <sub>OUT</sub> =0V		200		mA	
R <sub>PD</sub>	Pull-down resistance for CE pin		2.5	5.0	10.0	MΩ	
V <sub>CEH</sub>	CE Input Voltage "H"		1.2		V <sub>IN</sub>	V	
V <sub>CEL</sub>	CE Input Voltage "L"		0		0.25	V	
T <sub>TSD</sub>	Thermal Shutdown Detector Threshold Temperature	Junction Temperature		150		°C	
T <sub>TSR</sub>	Thermal Shutdown Released Temperature	Junction Temperature		120		°C	

### • Ripple Rejection by Output Voltage

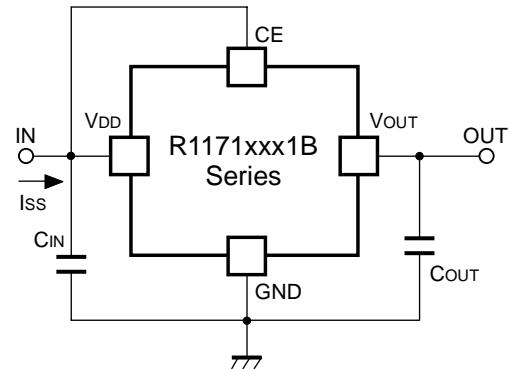
Topt=25°C

Output Voltage V <sub>OUT</sub> (V)	Ripple Rejection RR (dB)	
	Condition	Typ.
1.8 ≤ V <sub>OUT</sub> < 4.7	f=1kHz, Ripple 0.5Vp-p, V <sub>IN</sub> -V <sub>OUT</sub> =1.0V	50
4.7 ≤ V <sub>OUT</sub> ≤ 5.0	f=1kHz, Ripple 0.5Vp-p, V <sub>IN</sub> =5.75V	

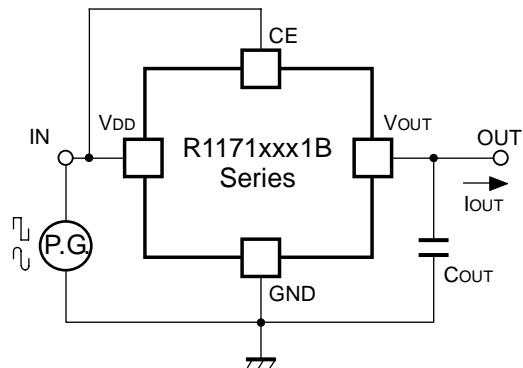
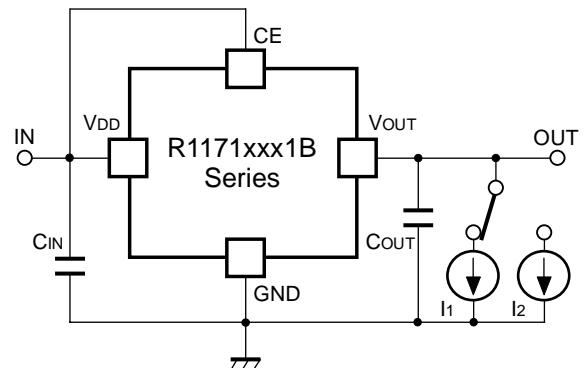
## TEST CIRCUITS



Standard Test Circuit



Supply Current Test Circuit

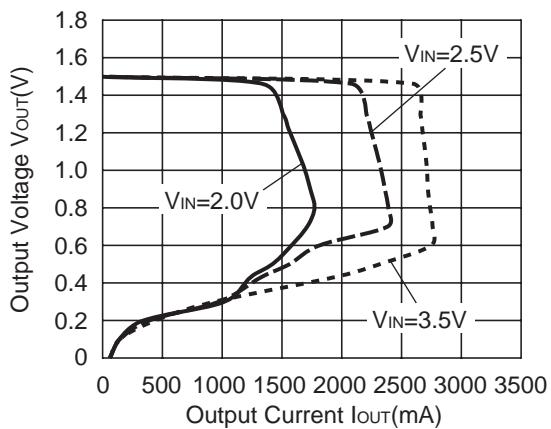
Test Circuit for Ripple Rejection,  
Input Transient Response

Test Circuit for Load Transient Response

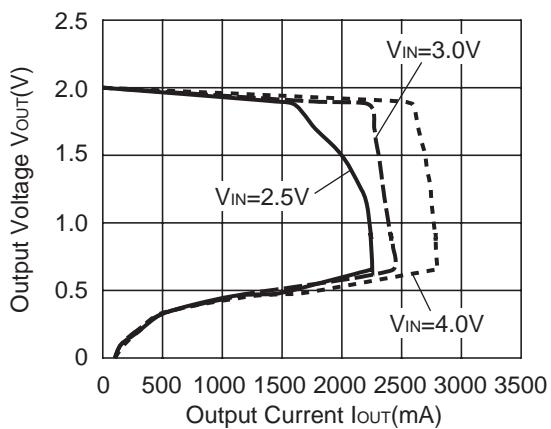
## TYPICAL CHARACTERISTICS

### 1) Output Voltage vs. Output Current ( $T_{opt}=25^{\circ}\text{C}$ )

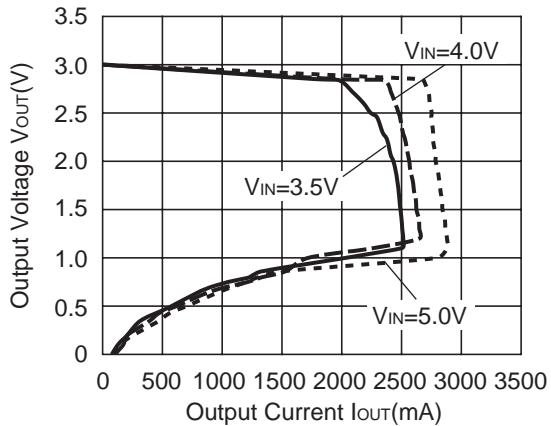
R1171S151x



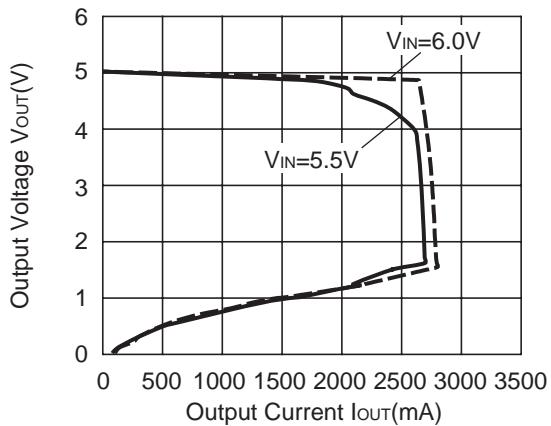
R1171S201x



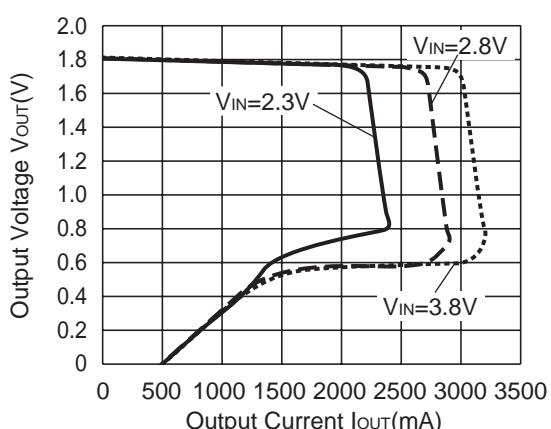
R1171S301x



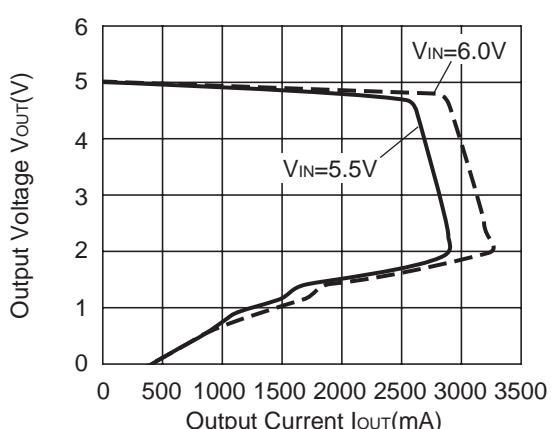
R1171S501x



R1171J181x

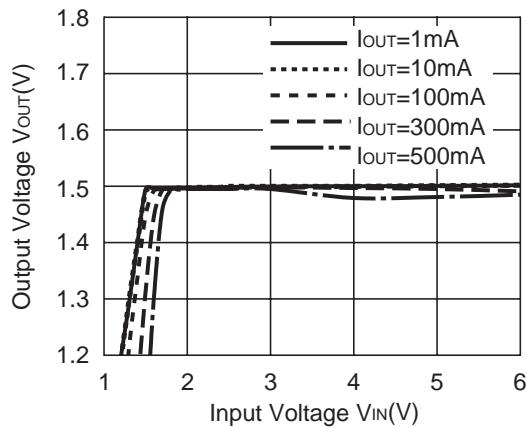


R1171J501x

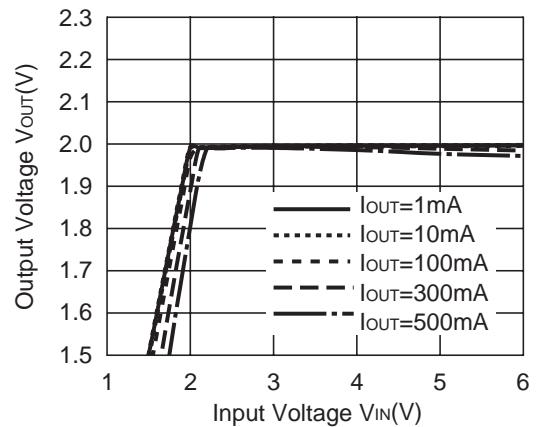


## 2) Output Voltage vs. Input Voltage ( $T_{opt}=25^{\circ}\text{C}$ )

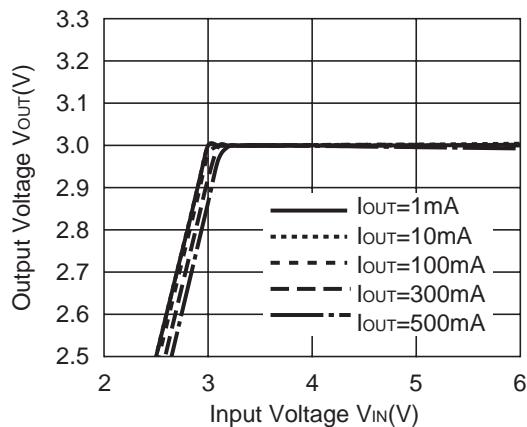
R1171x151B



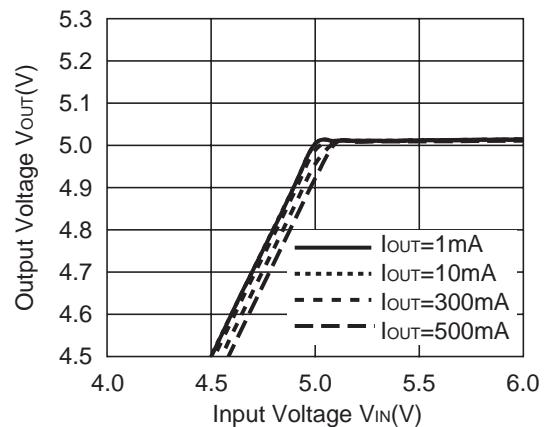
R1171x201B



R1171x301B

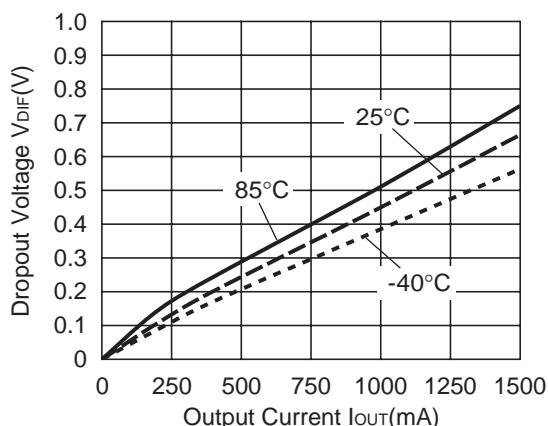


R1171x501B

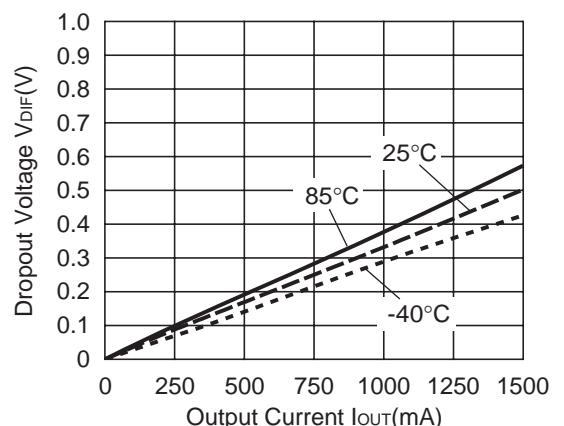


## 3) Dropout Voltage vs. Output Current

R1171S151x



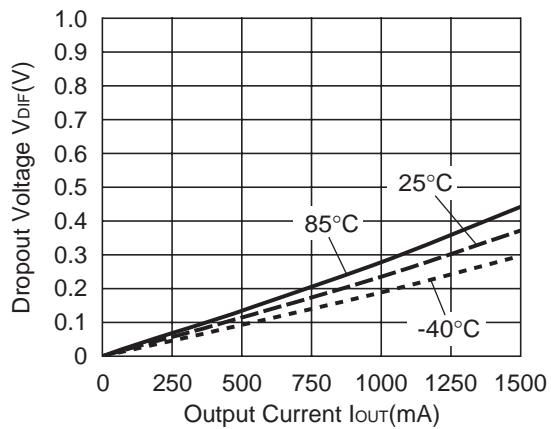
R1171S201x



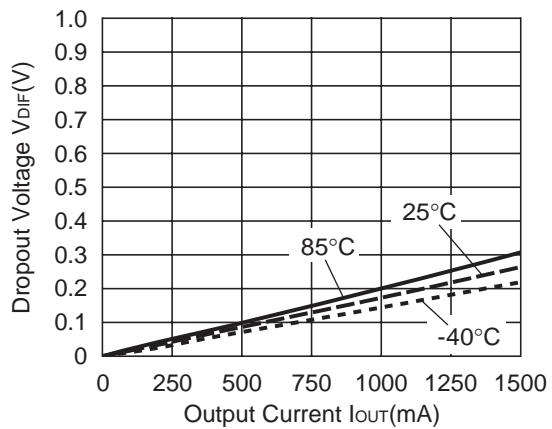
## R1171x

---

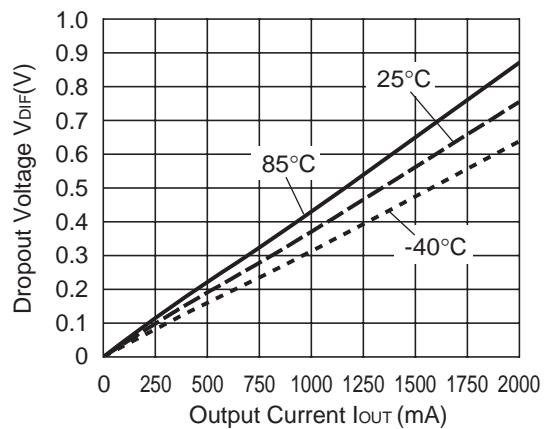
**R1171S301x**



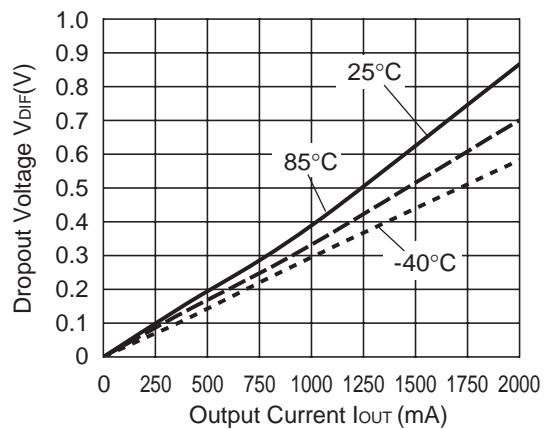
**R1171S501x**



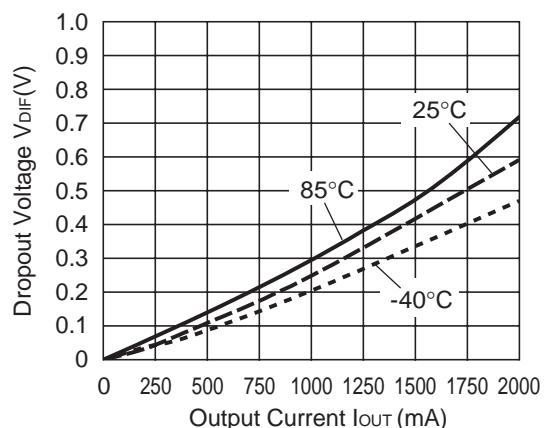
**R1171J181x**



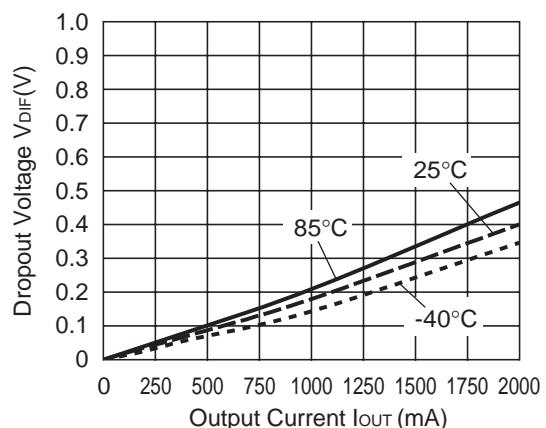
**R1171J201x**

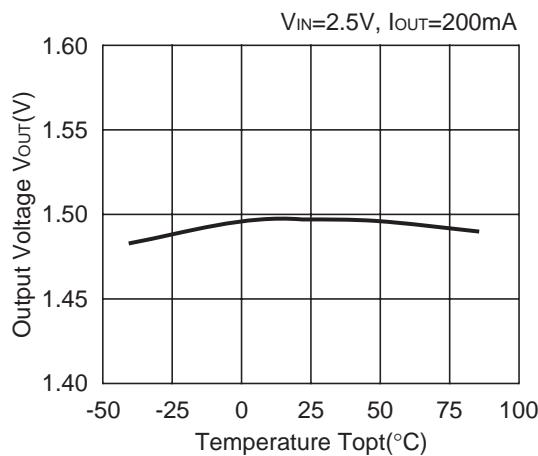
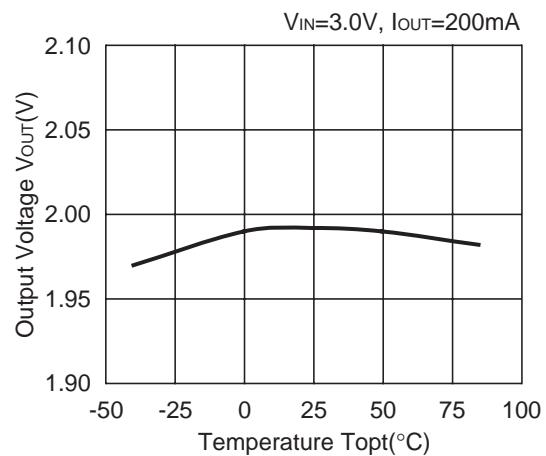
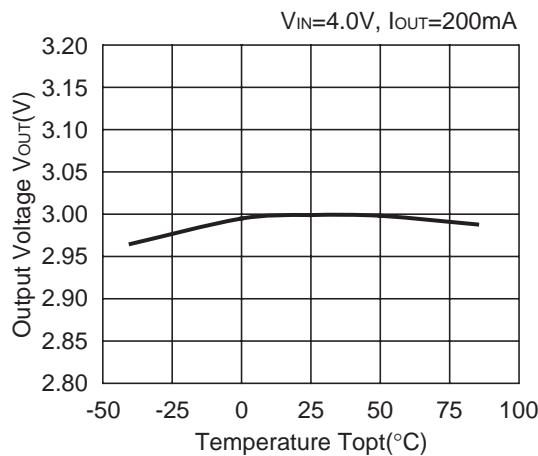
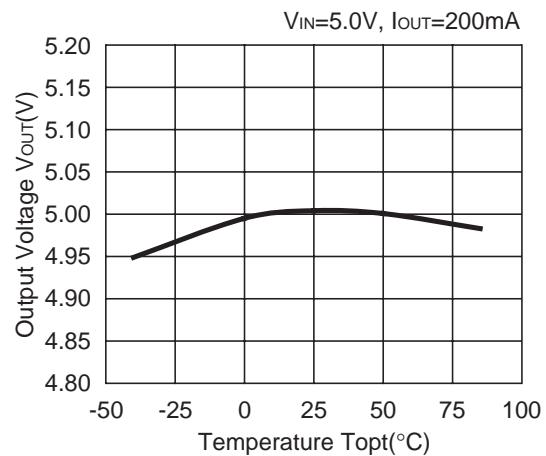
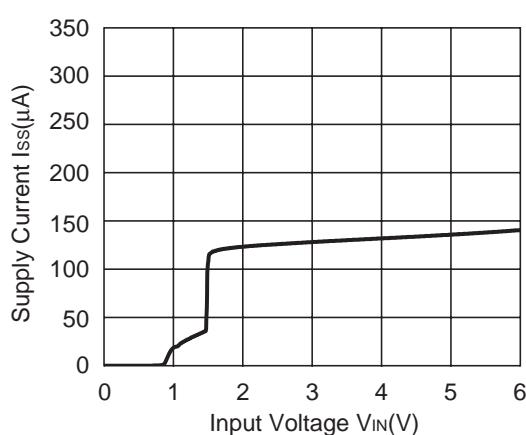
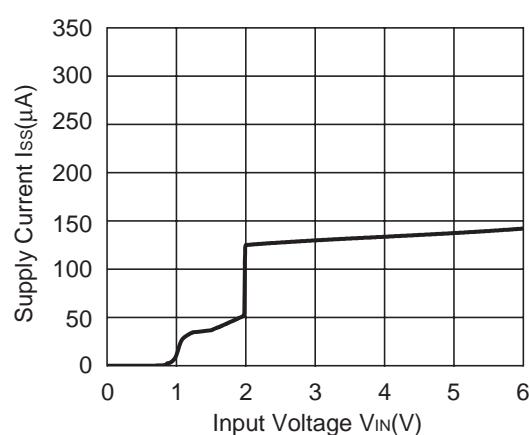


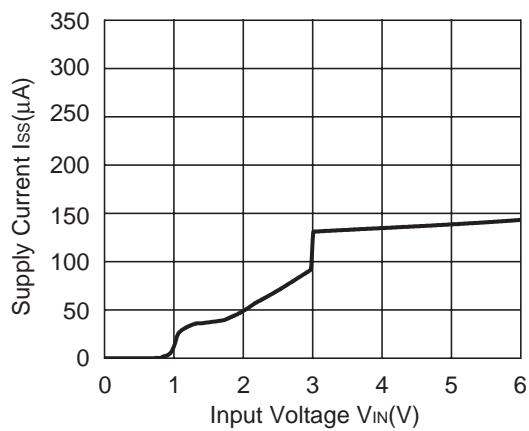
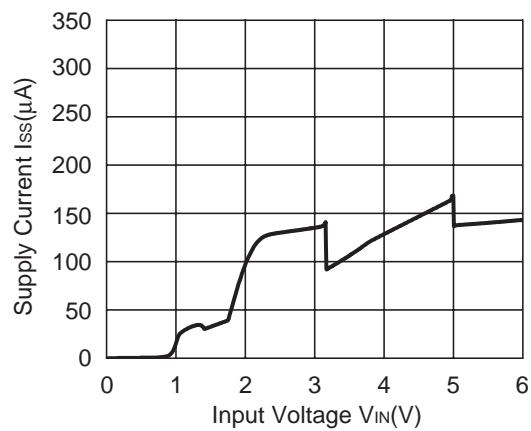
**R1171J301x**



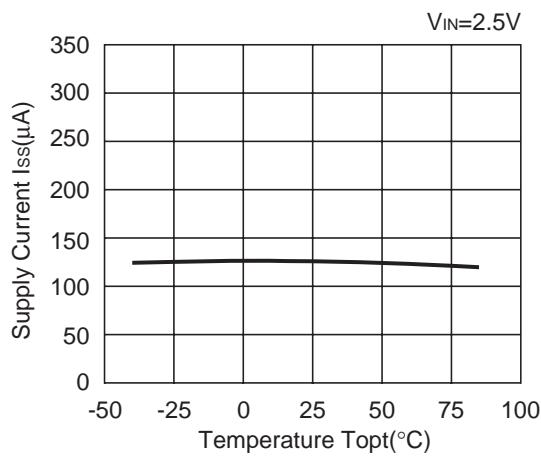
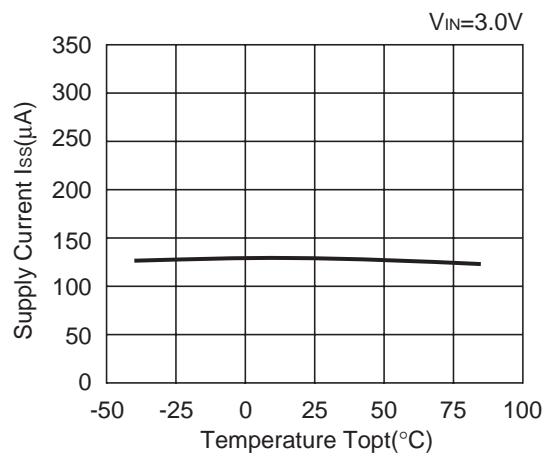
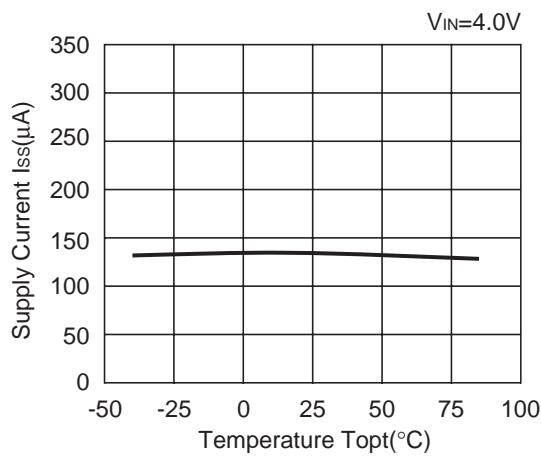
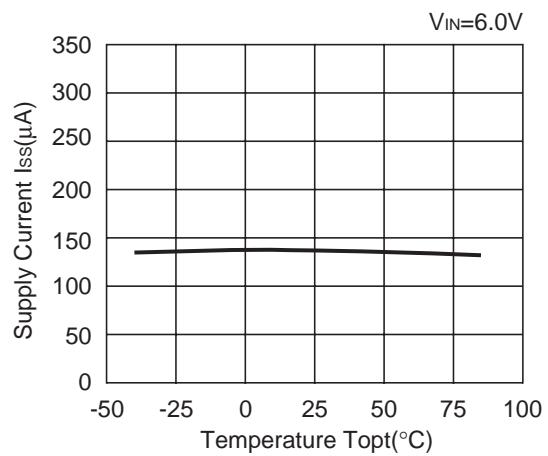
**R1171J501x**



**4) Output Voltage vs. Temperature****R1171x151B****R1171x201B****R1171x301B****R1171x501B****5) Supply Current vs. Input Voltage ( $T_{opt}=25^{\circ}C$ )****R1171x151B****R1171x201B**

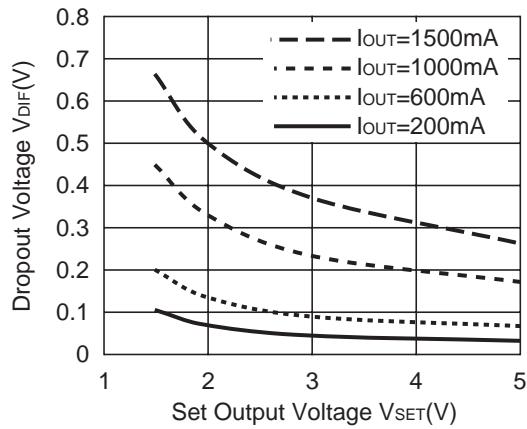
**R1171x301B****R1171x501B**

## 6) Supply Current vs. Temperature

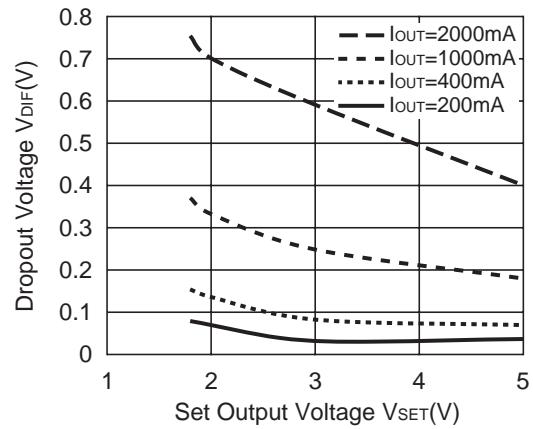
**R1171x151B****R1171x201B****R1171x301B****R1171x501B**

**7) Dropout Voltage vs. Set Output Voltage ( $T_{OPT}=25^{\circ}\text{C}$ )**

**R1171Sxx1x**

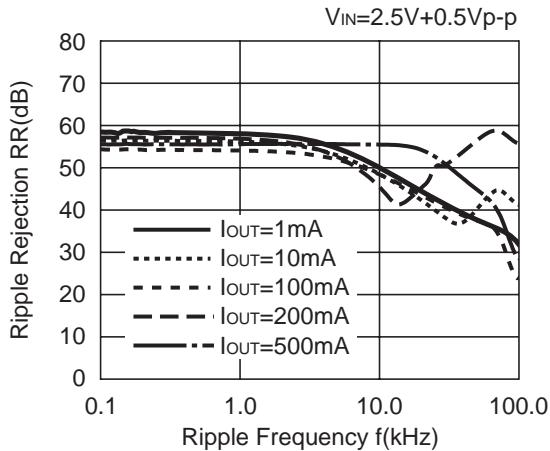


**R1171Jxx1x**

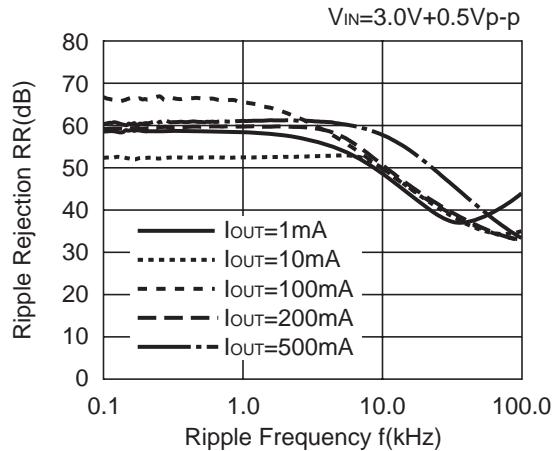


**8) Ripple Rejection vs. Frequency**

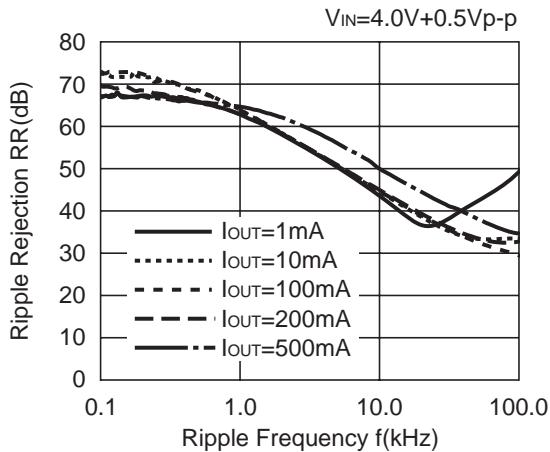
**R1171x151B**



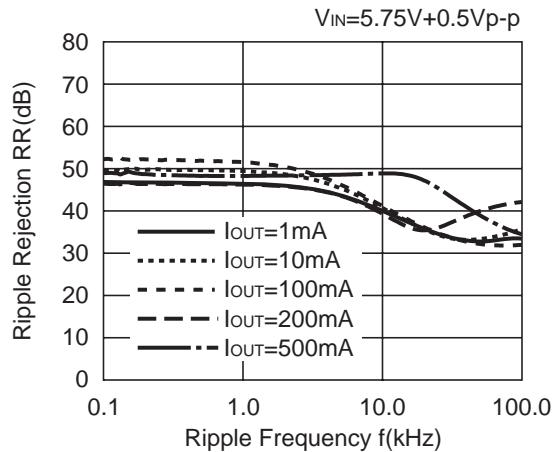
**R1171x201B**

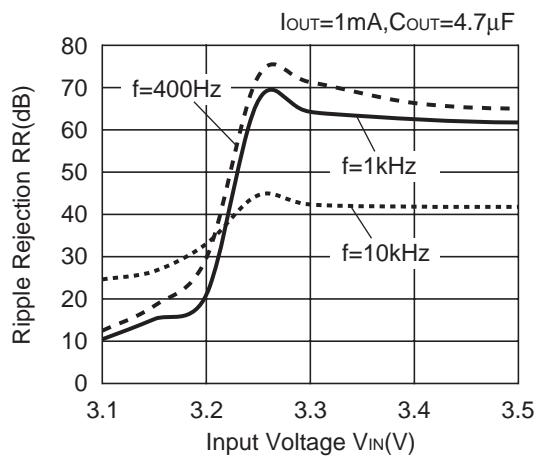
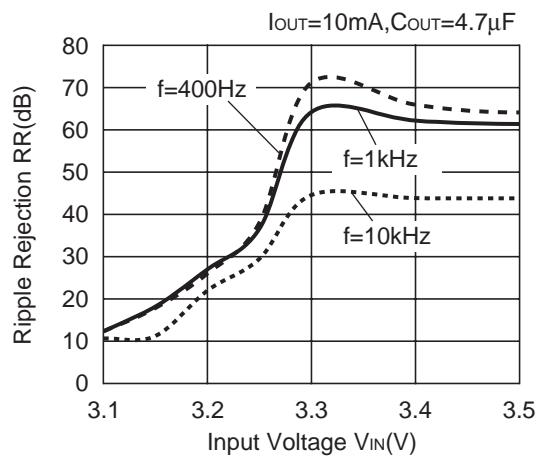
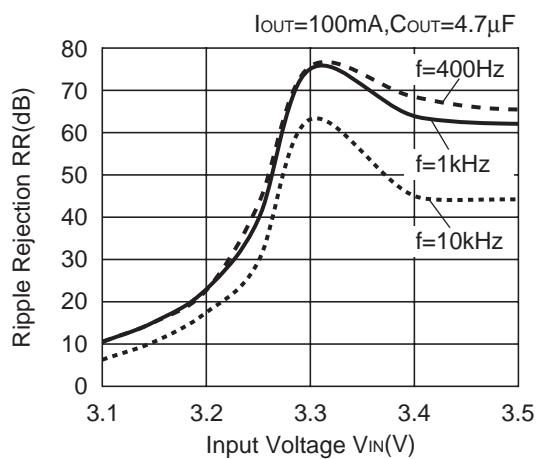
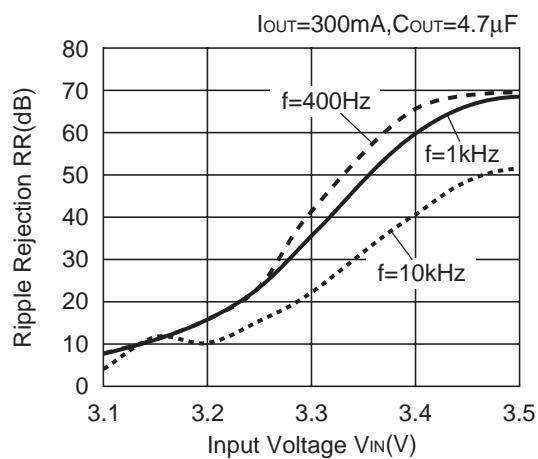
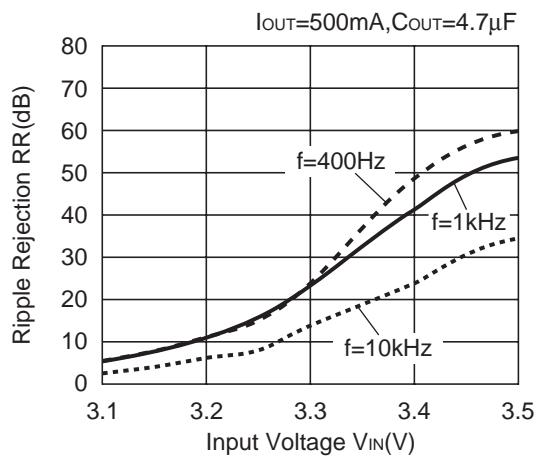


**R1171x301B**



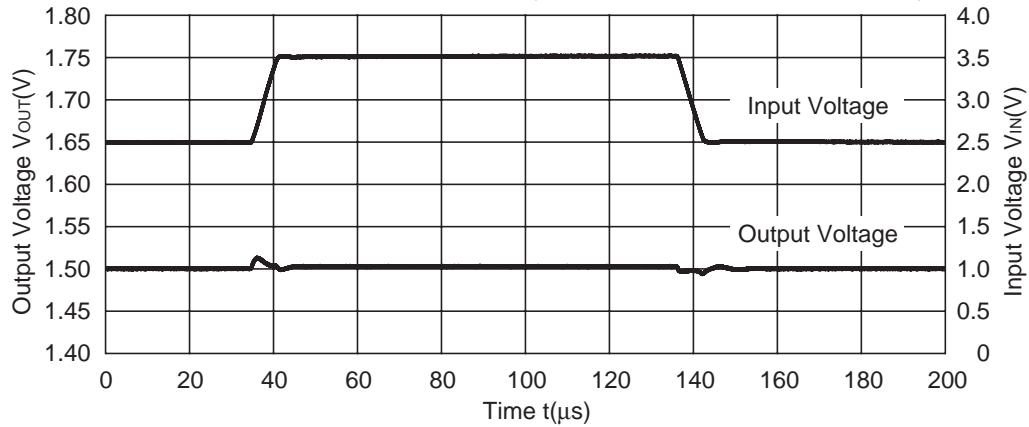
**R1171x501B**



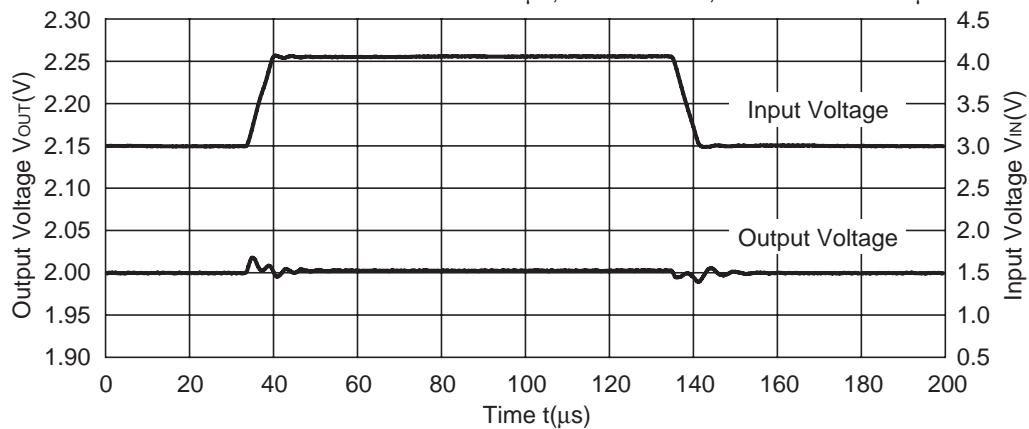
**9) Ripple Rejection vs. Input Voltage****R1171x301x****R1171x301x****R1171x301x****R1171x301x****R1171x301x**

10) Input Transient Response ( $T_{opt}=25^{\circ}\text{C}$ )

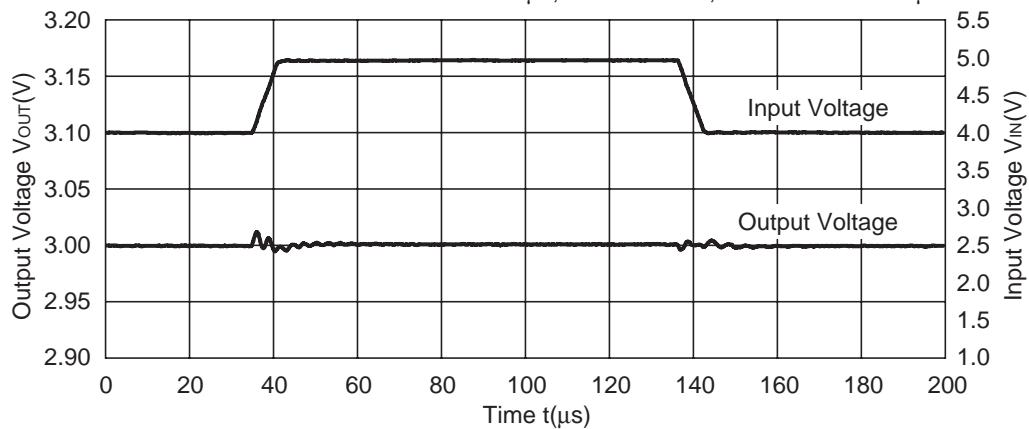
R1171x151B

 $\text{tr}=\text{tf}=5\mu\text{s}, \text{I}_{\text{OUT}}=1000\text{mA}, \text{C}_{\text{OUT}}=\text{Ceramic } 10\mu\text{F}$ 

R1171x201B

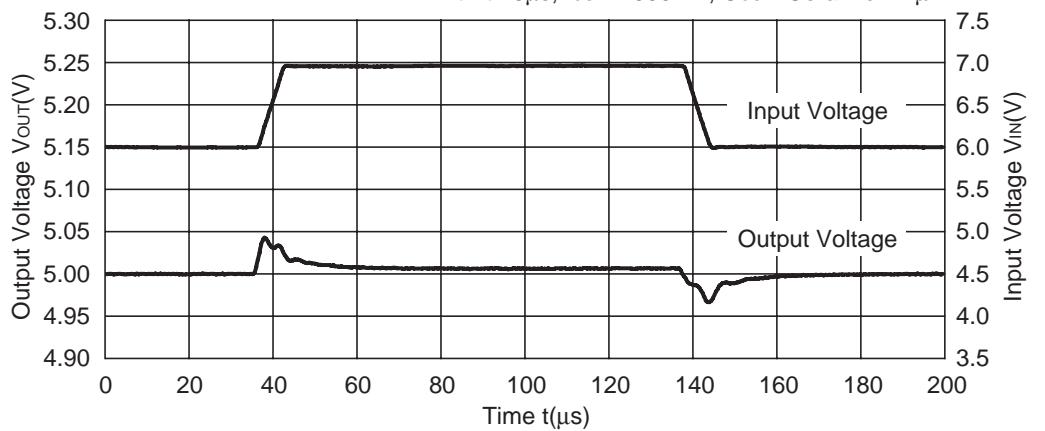
 $\text{tr}=\text{tf}=5\mu\text{s}, \text{I}_{\text{OUT}}=1000\text{mA}, \text{C}_{\text{OUT}}=\text{Ceramic } 4.7\mu\text{F}$ 

R1171x301B

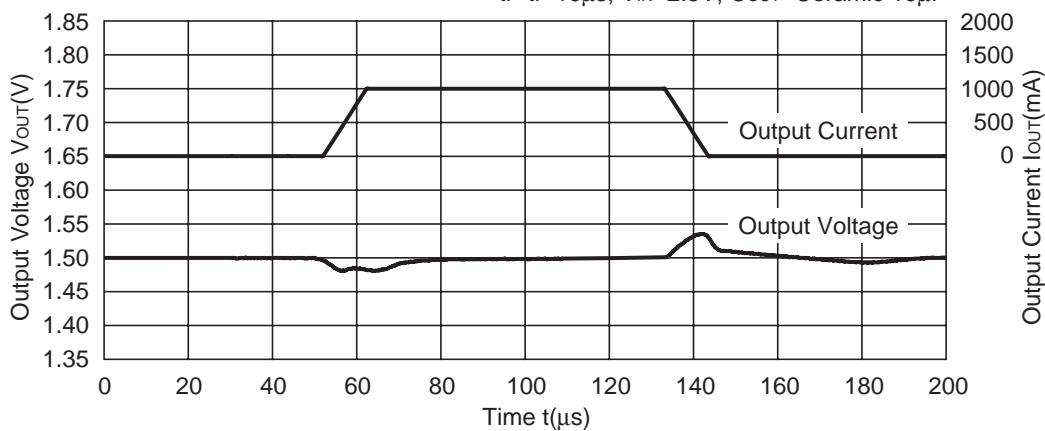
 $\text{tr}=\text{tf}=5\mu\text{s}, \text{I}_{\text{OUT}}=1000\text{mA}, \text{C}_{\text{OUT}}=\text{Ceramic } 4.7\mu\text{F}$ 

**R1171x501B**

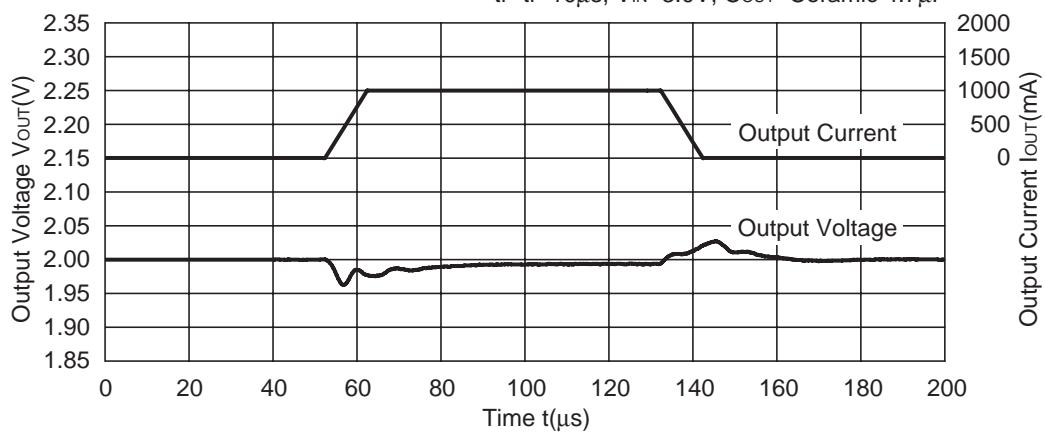
tr=tf=5μs, Iout=1000mA, Cout=Ceramic 4.7μF

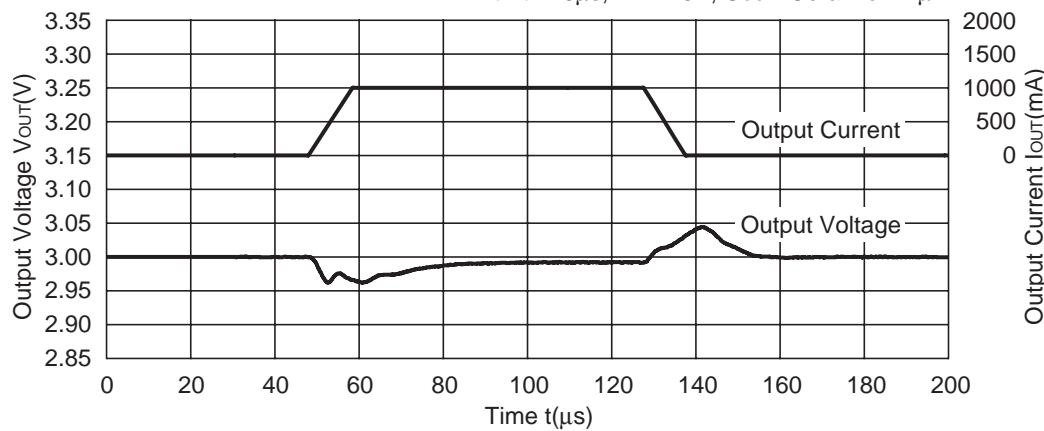
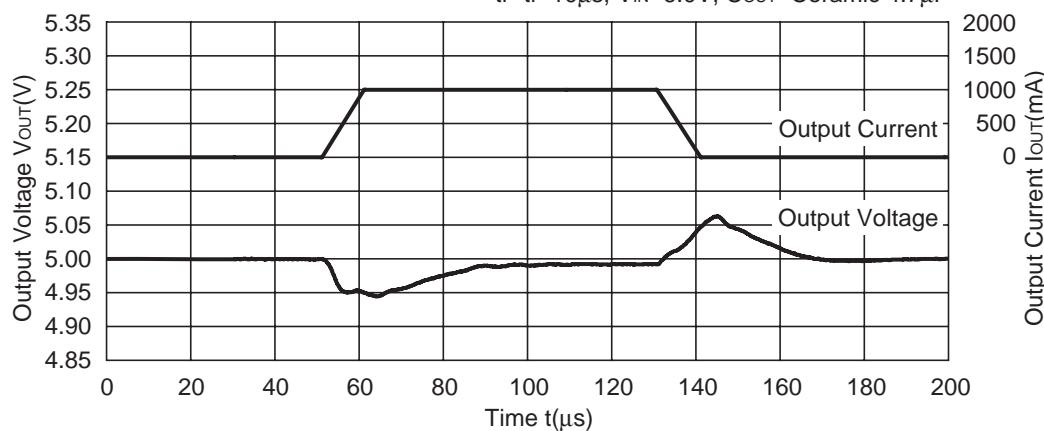
**11) Load Transient Response (Topt=25°C)****R1171x151B**

tr=tf=10μs, Vin=2.5V, Cout=Ceramic 10μF

**R1171x201B**

tr=tf=10μs, Vin=3.0V, Cout=Ceramic 4.7μF



**R1171x301B**tr=tf=10μs, V<sub>IN</sub>=4.0V, C<sub>OUT</sub>=Ceramic 4.7μF**R1171x501B**tr=tf=10μs, V<sub>IN</sub>=6.0V, C<sub>OUT</sub>=Ceramic 4.7μF

## Technical Notes on External Components and Typical Application

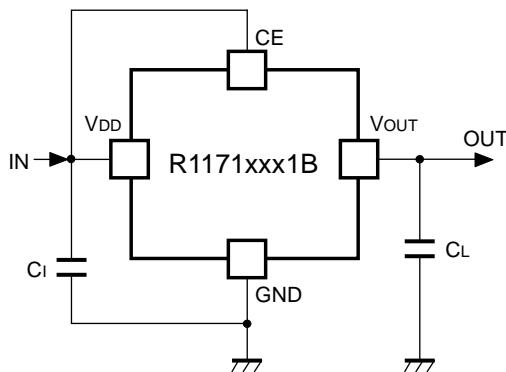
### 1. Phase Compensation

In these ICs, phase compensation is made with the output capacitor for securing stable operation even if the load current is varied. For this purpose, use a capacitor with the capacitance range from  $4.7\mu\text{F}$  to  $10.0\mu\text{F}$ , as  $C_L$ . In case that using a tantalum capacitor and the ESR of the tantalum capacitor is too large, unstable operation may result. Fully evaluation is necessary for the whole circuit with considering the frequency characteristic.

### 2. Mounting on PCB

Make  $V_{DD}$  and GND lines sufficient. If their impedance is high, large current may flow and the pick-up noise or unstable operation may result. Therefore use a capacitor with a capacitance range from  $4.7\mu\text{F}$  to  $10.0\mu\text{F}$  between  $V_{DD}$  pin and GND pin as close as possible.

Further, set an output capacitor between  $V_{OUT}$  pin and GND pin for phase compensation as close as possible. (Refer to the example of typical application)



R1171Sxx1B Typical Application

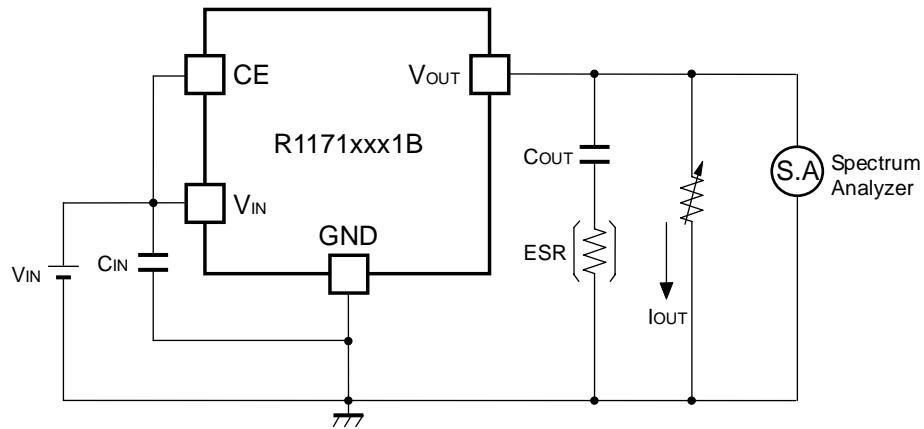
$1.5V \leq V_{OUT} < 1.8V : C_I = 10\mu\text{F}$  (Ceramic),  $C_L = 10\mu\text{F}$  (Ceramic)

$1.8V \leq V_{OUT} \leq 5.0V : C_I = 4.7\mu\text{F}$  (Ceramic),  $C_L = 4.7\mu\text{F}$  (Ceramic)

### 3. Output Short Protection Function

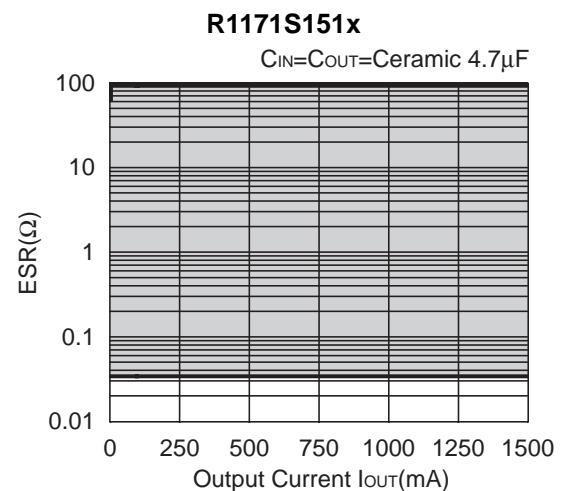
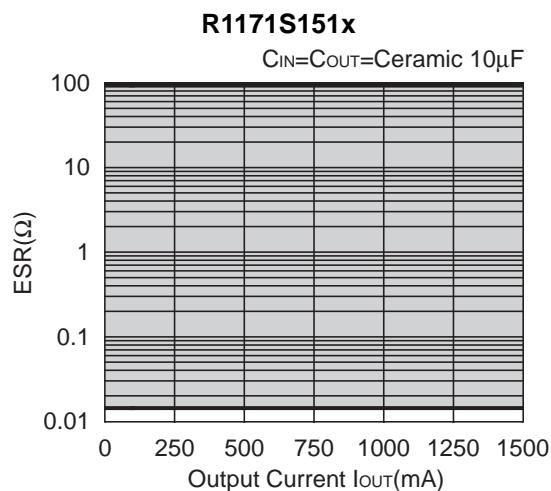
In the R1171x Series, the output short protection function is built in, further, if the output is short to the GND or other voltage line, the chip inside is heating, as a result, in case that the junction temperature becomes equal or more than  $150^\circ\text{C}$  (Typ.), the built-in thermal shutdown circuit works. If the junction temperature becomes equal or more than  $150^\circ\text{C}$  (Typ.), the IC is protected by the output short protection circuit and the thermal shutdown circuit.

## ESR vs. Output Current ( $T_{opt}=25^{\circ}\text{C}$ , $V_{IN}=\text{Set Output Voltage}+1\text{V}$ , $C_{IN}=\text{Ceramic } 10\mu\text{F}$ )



As an output capacitor for this IC, Ceramic capacitor is recommendable. However, other low ESR type capacitor can be used with this IC.

For your reference, noise level is tested with the circuit as shown above, and if the noise level is  $40\mu\text{V}$  or less than  $40\mu\text{V}$ , the ESR values are plotted as stable area. Upper limit is described in the next four graphs, or ESR vs. Output Current. (Hatched area is the stable area.)

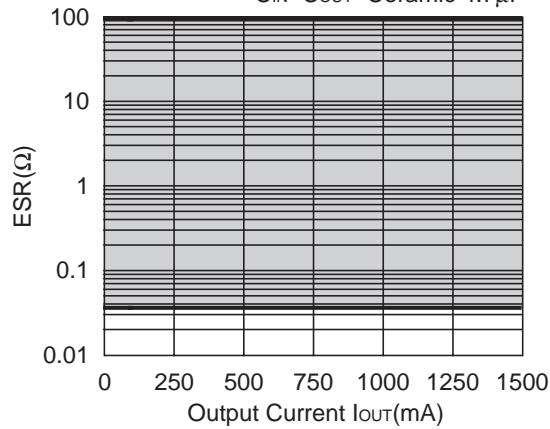


## R1171x

---

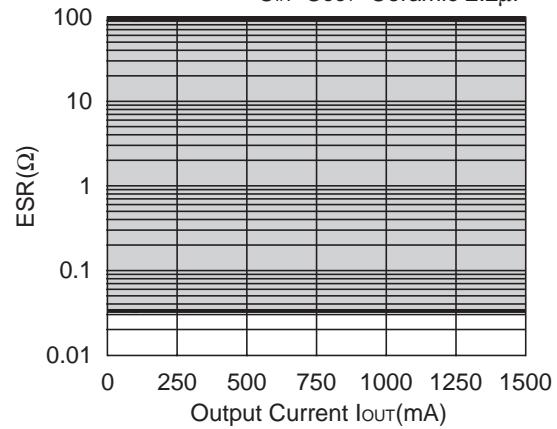
**R1171S301x**

$C_{IN}=C_{OUT}=\text{Ceramic } 4.7\mu\text{F}$



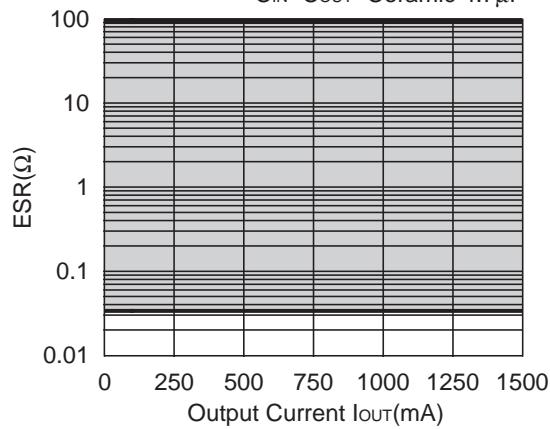
**R1171S301x**

$C_{IN}=C_{OUT}=\text{Ceramic } 2.2\mu\text{F}$



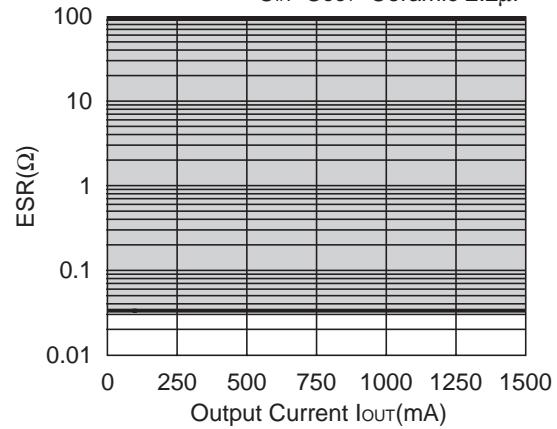
**R1171S501x**

$C_{IN}=C_{OUT}=\text{Ceramic } 4.7\mu\text{F}$



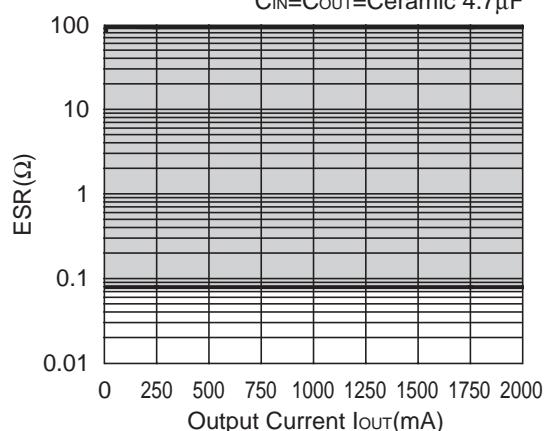
**R1171S501x**

$C_{IN}=C_{OUT}=\text{Ceramic } 2.2\mu\text{F}$



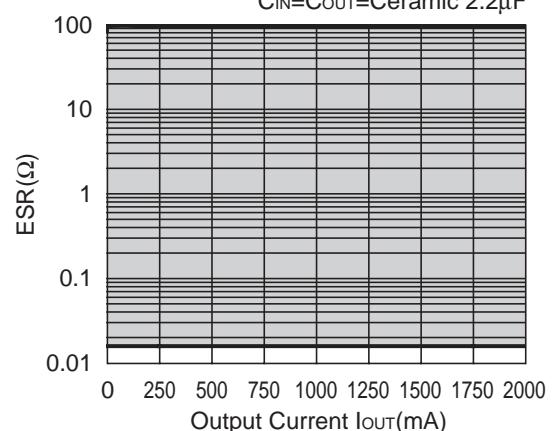
**R1171J181x**

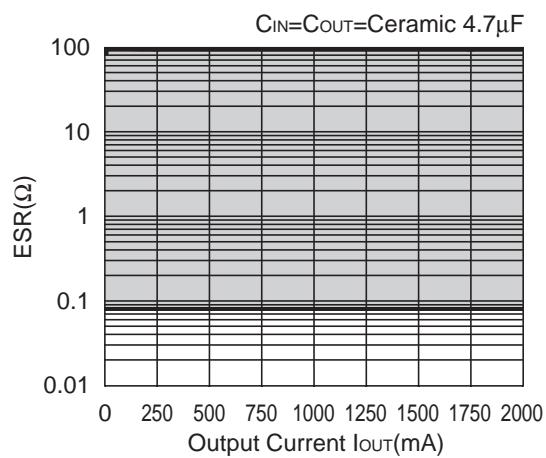
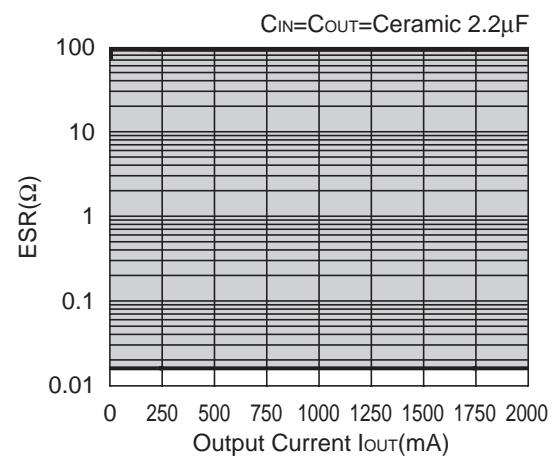
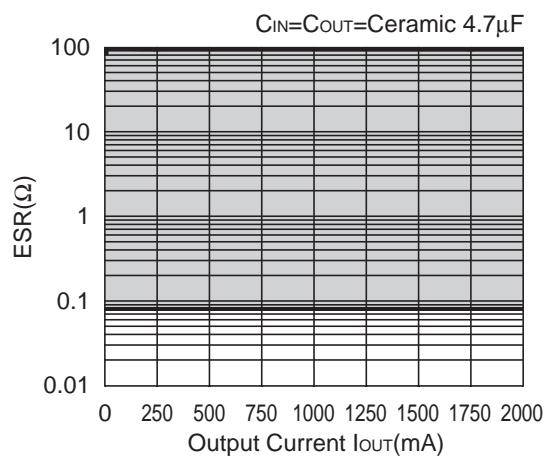
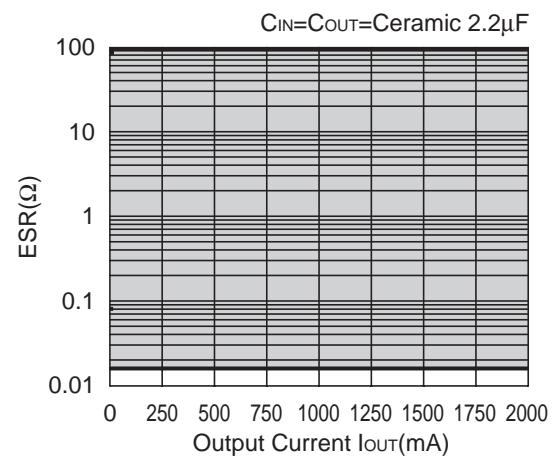
$C_{IN}=C_{OUT}=\text{Ceramic } 4.7\mu\text{F}$



**R1171J181x**

$C_{IN}=C_{OUT}=\text{Ceramic } 2.2\mu\text{F}$



**R1171J301x****R1171J301x****R1171J501x****R1171J501x**



1. The products and the product specifications described in this document are subject to change or discontinuation of production without notice for reasons such as improvement. Therefore, before deciding to use the products, please refer to Ricoh sales representatives for the latest information thereon.
2. The materials in this document may not be copied or otherwise reproduced in whole or in part without prior written consent of Ricoh.
3. Please be sure to take any necessary formalities under relevant laws or regulations before exporting or otherwise taking out of your country the products or the technical information described herein.
4. The technical information described in this document shows typical characteristics of and example application circuits for the products. The release of such information is not to be construed as a warranty of or a grant of license under Ricoh's or any third party's intellectual property rights or any other rights.
5. The products listed in this document are intended and designed for use as general electronic components in standard applications (office equipment, telecommunication equipment, measuring instruments, consumer electronic products, amusement equipment etc.). Those customers intending to use a product in an application requiring extreme quality and reliability, for example, in a highly specific application where the failure or misoperation of the product could result in human injury or death (aircraft, spacevehicle, nuclear reactor control system, traffic control system, automotive and transportation equipment, combustion equipment, safety devices, life support system etc.) should first contact us.
6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
7. Anti-radiation design is not implemented in the products described in this document.
8. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
9. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
10. There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact Ricoh sales or our distributor before attempting to use AOI.
11. Please contact Ricoh sales representatives should you have any questions or comments concerning the products or the technical information.



**Ricoh is committed to reducing the environmental loading materials in electrical devices with a view to contributing to the protection of human health and the environment.**

Ricoh has been providing RoHS compliant products since April 1, 2006 and Halogen-free products since April 1, 2012.

## **RICOH RICOH ELECTRONIC DEVICES CO., LTD.**

<https://www.e-devices.ricoh.co.jp/en/>

### **Sales & Support Offices**

#### **Ricoh Electronic Devices Co., Ltd.**

**Shin-Yokohama Office (International Sales)**  
2-3, Shin-Yokohama 3-chome, Kohoku-ku, Yokohama-shi, Kanagawa, 222-8530, Japan  
Phone: +81-50-3814-7687 Fax: +81-45-474-0074

#### **Ricoh Americas Holdings, Inc.**

675 Campbell Technology Parkway, Suite 200 Campbell, CA 95008, U.S.A.  
Phone: +1-408-610-3105

#### **Ricoh Europe (Netherlands) B.V.**

**Semiconductor Support Centre**  
Prof. W.H. Keesomlaan 1, 1183 DJ Amstelveen, The Netherlands  
Phone: +31-20-5474-309

#### **Ricoh International B.V. - German Branch**

**Semiconductor Sales and Support Centre**  
Oberrather Strasse 6, 40472 Düsseldorf, Germany  
Phone: +49-211-6546-0

#### **Ricoh Electronic Devices Korea Co., Ltd.**

3F, Haesung Bldg, 504, Teheran-ro, Gangnam-gu, Seoul, 135-725, Korea  
Phone: +82-2-2135-5700 Fax: +82-2-2051-5713

#### **Ricoh Electronic Devices Shanghai Co., Ltd.**

Room 403, No.2 Building, No.690 Bibo Road, Pu Dong New District, Shanghai 201203,  
People's Republic of China  
Phone: +86-21-5027-3200 Fax: +86-21-5027-3299

#### **Ricoh Electronic Devices Shanghai Co., Ltd.**

**Shenzhen Branch**  
1205, Block D(Jinlong Building), Kingkey 100, Hongbao Road, Luohu District,  
Shenzhen, China  
Phone: +86-755-8348-7600 Ext 225

#### **Ricoh Electronic Devices Co., Ltd.**

**Taipei office**  
Room 109, 10F-1, No.51, Hengyang Rd., Taipei City, Taiwan (R.O.C.)  
Phone: +886-2-2313-1621/1622 Fax: +886-2-2313-1623

# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

***Click to view similar products for LDO Voltage Regulators category:***

***Click to view products by Nissinbo manufacturer:***

Other Similar products are found below :

[AP7363-SP-13](#) [L79M05TL-E](#) [PT7M8202B12TA5EX](#) [TCR3DF185,LM\(CT](#) [TCR3DF24,LM\(CT](#) [TCR3DF285,LM\(CT](#) [TCR3DF31,LM\(CT](#)  
[TCR3DF45,LM\(CT](#) [MP2013GQ-33-Z](#) [059985X](#) [NCP4687DH15T1G](#) [701326R](#) [TCR2EN28,LF\(S](#) [NCV8170AXV250T2G](#)  
[TCR3DF27,LM\(CT](#) [TCR3DF19,LM\(CT](#) [TCR3DF125,LM\(CT](#) [TCR2EN18,LF\(S](#) [AP2112R5A-3.3TRG1](#) [AP7315-25W5-7](#)  
[IFX30081LDVGRNXUMA1](#) [NCV47411PAAJR2G](#) [AP2113KTR-G1](#) [AP2111H-1.2TRG1](#) [ZLDO1117QK50TC](#) [AZ1117IH-1.8TRG1](#)  
[AZ1117ID-ADJTRG1](#) [TCR3DG12,LF](#) [MIC5514-3.3YMT-T5](#) [MIC5512-1.2YMT-T5](#) [MIC5317-2.8YM5-T5](#) [SCD7912BTG](#)  
[NCP154MX180270TAG](#) [SCD33269T-5.0G](#) [NCV8170BMX330TCG](#) [NCV8170AMX120TCG](#) [NCP706ABMX300TAG](#)  
[NCP153MX330180TCG](#) [NCP114BMX075TCG](#) [MC33269T-3.5G](#) [CAT6243-ADJCMT5T](#) [TCR3DG33,LF](#) [AP2127N-1.0TRG1](#)  
[TCR4DG35,LF](#) [TAR5S15U\(TE85L,F\)](#) [TAR5S18U\(TE85L,F\)](#) [TCR3UG19A,LF](#) [TCR4DG105,LF](#) [NCV8170AMX360TCG](#) [MIC94310-NYMT-T5](#)